General Description

The MAX4335–MAX4338 op amps deliver 40mW per channel into 32Ω from ultra-small SC70/SOT23 packages making them ideal for mono/stereo headphone drivers in portable applications. These amplifiers have a 5MHz gain-bandwidth product and are guaranteed to deliver 50mA of output current while operating from a single supply of 2.7V to 5.5V.

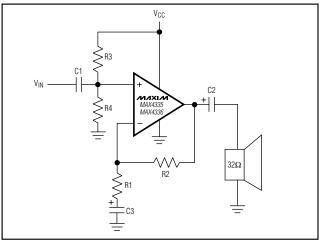
The MAX4336 and the MAX4338 have a shutdown/mute mode that reduces the supply current to 0.04μ A per amplifier and places the outputs in a high-impedance state.

The MAX4335–MAX4338 have 90dB power-supply rejection ratio (PSRR), eliminating the need for costly pre-regulation in most audio applications. Both the input voltage range and the output voltage swing include both supply rails, maximizing dynamic range.

The MAX4335/MAX4336 single amplifiers are available in ultra-small 6-pin SC70 packages. The MAX4337/MAX4338 dual amplifiers are available in an 8-pin SOT23 and a 10-pin μ MAX package, respectively. All devices are specified from -40°C to +85°C.

-		
App	1100	tione
AUU		tions

32Ω Headphone Drivers Portable/Battery-Powered Instruments Wireless PA Control Hands-Free Car Phones Transformer/Line Drivers DAC/ADC Buffers



Typical Operating Circuit

Rail-to-Rail is a registered trademark of Nippon Motorola Ltd.

M/X/W

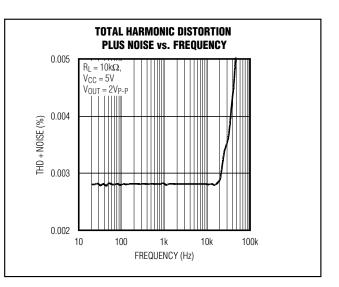
Features

- ♦ 50mA Output Drive Capability
- Low 0.003% THD (20kHz into 10kΩ)
- ♦ Rail-to-Rail[®] Inputs and Outputs
- ♦ 2.7V to 5.5V Single-Supply Operation
- ♦ 5MHz Gain-Bandwidth Product
- ♦ 95dB Large-Signal Voltage Gain
- ♦ 90dB Power-Supply Rejection Ratio
- No Phase Reversal for Overdrive Inputs
- Ultra-Low Power Shutdown/Mute Mode Reduces Supply Current to 0.04µA Places Output in High-Impedance State
- Thermal Overload Protection

PART	TEMP RANGE	PIN- PACKAGE	TOP MARK
MAX4335EXT-T	-40°C to +85°C	6 SC70-6	AAX
MAX4336EXT-T	-40°C to +85°C	6 SC70-6	AAW
MAX4337EKA-T	-40°C to +85°C	8 SOT23-8	AAIK
MAX4337EUA	-40°C to +85°C	8 µMAX	_
MAX4338EUB	-40°C to +85°C	10 µMAX	—

Ordering Information

Pin Configurations appear at end of data sheet.



Maxim Integrated Products 1

For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

ABSOLUTE MAXIMUM RATINGS

Supply Voltage (V_{CC} to GND)-0.3V to +6V All Other Pins to GND(GND - 0.3V) to (V_{CC} + 0.3V) Output Short-Circuit Duration to V_{CC} or GNDContinuous Continuous Power Dissipation (T_A = +70°C)

6-Pin SC70 (d	lerate 3.1mW/°C above +70°C)	245mW
8-Pin SOT23 (derate 9.1mW/°C above +70°C)	727mW

8-Pin µMAX (derate 4.5mW/°C above +70°C)362mW
10-Pin µMAX (derate 5.6mW/°C above +70°C	C)444mW
Operating Temperature Range	40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

(V_{CC} = 2.7V, GND = 0, V_{CM} = 0, V_{OUT} = V_{CC}/2, R_L = ∞ to V_{CC}/2, V_{SHDN} = V_{CC}, T_A = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIO	ONS	MIN	ΤΥΡ	MAX	UNITS
Operating Supply Voltage Range	Vcc	Inferred from PSRR	Test	2.7		5.5	V
Quiescent Supply Current (Per	laa	$V_{CC} = 5.5V$			1.3	1.8	m (
Amplifier)	Icc	V _{CC} = 2.7			1.2		mA
Input Offset Voltage	Vos	$V_{CM} = GND$ to V_{CC}			±0.6	±3	mV
Input Bias Current	Ι _Β	$V_{CM} = GND$ to V_{CC}			±100	±400	nA
Input Offset Current	los	$V_{CM} = GND$ to V_{CC}			±7	±30	nA
Differential Input Resistance	RIN(Diff)	$ V_{IN-} - V_{IN+} < 1.2V$			500		kΩ
Diferential input hesistance	UN(DIΠ)	$ _{VIN-} - V_{IN+} > 1.2V$			8.4		1/22
Input Common-Mode Voltage Range	V _{CM}	Inferred from CMRF	R Test	GND		V _{CC}	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = GND$ to V_{CC}		60	80		dB
Power-Supply Rejection Ratio	PSRR	$V_{CC} = 2.7V \text{ to } 5.5V$		70	90		dB
Output Resistance	R _{OUT}	$AV_{CL} = 1V/V$			0.05		Ω
	$V_{CC} = 5V: R_L = 10k\Omega$ $V_{OUT} = 0.4V \text{ to } 4.6V$				95		
Large-Signal Voltage Gain	Avol	$V_{CC} = 5V: R_L = 100\Omega$ $V_{OUT} = 0.5V \text{ to } 4.5V$		70	84		dB
		$V_{CC} = 2.7V: R_L = 32\Omega$ $V_{OUT} = 0.5V \text{ to } 2.2V$		62	72		
		$V_{\rm CC} = 2.7 V;$	V _{CC} - V _{OH}		100		
		$R_L = 10k\Omega$	VOL		100		
		$V_{CC} = 2.7V;$	V _{CC} - V _{OH}		220	400	
Output Voltage Swing	Vour	$R_L = 32\Omega$	VOL		280	400	mV
	Vout	$V_{CC} = 5V;$	V _{CC} - V _{OH}		100		
		$R_L = 10k\Omega$	V _{OL}		100		
		$V_{CC} = 5V;$	V _{CC} - V _{OH}		190	350	
		$R_L = 100\Omega$			240	350	

DC ELECTRICAL CHARACTERISTICS (continued)

(V_{CC} = 2.7V, GND = 0, V_{CM} = 0, V_{OUT} = V_{CC}/2, R_L = ∞ to V_{CC}/2, V_{SHDN} = V_{CC}, **T_A** = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIC	NS	MIN	ТҮР	MAX	UNITS
		V _{CC} = 2.7V;	V _{CC} - V _{OH}		270	500	
	lour	ISOURCE, ISINK = 50mA	V _{OL}		360	500	mV
Output Drive	IOUT	$V_{CC} = 5V;$	V _{CC} - V _{OH}		270	500	IIIV
		ISOURCE, ISINK = 50mA	V _{OL}		360	500	
Short-Circuit Current	Isc				110		mA
	VIH	Normal mode		0.7 x V _{CC}			V
SHDN Logic Levels	VIL	Shutdown mode				0.3 x V _{CC}	v
SHDN Leakage Current	١ _١ ٢	$V_{CC} = 5V, GND < V_{CC}$	SHDN < VCC			0.5	μA
Output Leakage Current in Shutdown	IOUT(SHDN)	$V_{CC} = 5V, V_{\overline{SHDN}} = 0, V_{OUT} = 0, V_{CC}$			0.01	0.5	μA
Shutdown Supply Current (Per Amplifier)	ICC(SHDN)	$\overline{\text{SHDN}} = \text{GND}; V_{\text{CC}} = 5V$			<0.04	0.5	μA

DC ELECTRICAL CHARACTERISTICS

(V_{CC} = 2.7V, GND = 0, V_{CM} = 0, V_{OUT} = V_{CC}/2, R_L = ∞ to V_{CC}/2, V_{SHDN} = V_{CC}, T_A = -40°C to +85°C, unless otherwise noted.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	МАХ	UNITS
Operating Supply Voltage Range	V _{CC}	Inferred from PSRR test	2.7		5.5	V
Quiescent Supply Current (Per Amplifier)	Icc	$V_{\rm CC} = 5.5 V$			2.25	mA
Input Offset Voltage	Vos	$V_{CM} = GND$ to V_{CC}			±6	mV
Input Bias Current	Ι _Β	$V_{CM} = GND$ to V_{CC}			±600	nA
Input Offset Current	I _{OS}	$V_{CM} = GND$ to V_{CC}			±60	nA
Input Common-Mode Voltage Range	VCM	Inferred from CMRR test	GND		V _{CC}	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = GND$ to V_{CC}	50			dB
Power-Supply Rejection Ratio	PSRR	$V_{CC} = 2.7V$ to 5.5V	64			dB
Large-Signal Voltage Gain	Avol	$V_{CC} = 5V: R_L = 100\Omega,$ $V_{OUT} = 0.6V \text{ to } 4.4V$	66			dB
		$\label{eq:VCC} \begin{split} V_{CC} &= 2.7 \text{V}: \text{R}_L = 32 \Omega, \\ V_{OUT} &= 0.6 \text{V to } 2.1 \text{V} \end{split}$	56			UB

DC ELECTRICAL CHARACTERISTICS (continued)

(V_{CC} = 2.7V, GND = 0, V_{CM} = 0, V_{OUT} = V_{CC}/2, R_L = ∞ to V_{CC}/2, V_{SHDN} = V_{CC}, T_A = -40°C to +85°C, unless otherwise noted.) (Note 1)

PARAMETER	SYMBOL	COND	ITIONS	MIN	ТҮР	МАХ	UNITS
		$V_{CC} = 2.7V;$	V _{CC} - V _{OH}			500	
Output Voltage Swing	Vour	$R_L = 32\Omega$	VOL			500	mV
Output Voltage Swing	Vout	$V_{CC} = 5V;$	VCC - VOH			400	IIIV
		$R_L = 100\Omega$	V _{OL}			400	
Output Drive		$V_{CC} = 2.7V;$	V _{CC} - V _{OH}			650	
		ISOURCE, ISINK = 50mA	V _{OL}			650	mV
	IOUT	V _{CC} = 5V; I _{SOURCE} , I _{SINK} = 50mA	VCC - VOH			650	
			Vol			650	
	VIH	Normal mode		0.7 x V _{CC}			V
SHDN Logic Level	VIL	Shutdown mode				0.3 x V _{CC}	V
SHDN Leakage Current	Ι _Ι Γ	V _{CC} = 5V, GND < V _{SHDN} < V _{CC}				1	μΑ
Output Leakage Current in Shutdown	IOUT(SHDN)	$V_{CC} = 5V, V_{\overline{SHDN}} = 0, V_{OUT} = 0;$ V_{CC}				1	μA
Shutdown Supply Current (Per Amplifier)	I _{CC} (SHDN)	$V_{\overline{SHDN}} = 0; V_{CC} =$: 5V			1	μA

AC ELECTRICAL CHARACTERISTICS

(V_{CC} = 2.7V, GND = 0, V_{CM} = V_{CC}/2, V_{OUT} = V_{CC}/2, V_{SHDN} = V_{CC}, A_{VCL} = 1V/V, C_L = 15pF, R_L = ∞ to V_{CC}/2, T_A = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDIT	MIN TYP	MAX	UNITS	
Gain-Bandwidth Product	GBWP			5		MHz
Full-Power Bandwidth	FBWP	$V_{OUT} = 2V_{P-P}, V_{CC} = 5V_{P-P}$	/	280		kHz
Slew Rate	SR			1.8		V/µs
Phase Margin	PM			70		degrees
Gain Margin	GM			18		dB
		$V_{CC} = 5V, R_L = 100\Omega,$ $V_{OUT} = 2V_{P-P}$	f = 1kHz	0.005		
			f = 10kHz	0.02		
Total Harmonic Distortion	THD	$V_{CC} = 5V, R_L = 10k\Omega, V_{OUT} = 2V_{P-P},$ f = 10kHz		0.003		%
		$V_{CC} = 2.7V;$	f = 1kHz	0.01		
		$R_{L} = 32\Omega,$ $V_{OUT} = 2V_{P-P}$	f = 10kHz	0.03		

M/IXI/M

AC ELECTRICAL CHARACTERISTICS (continued)

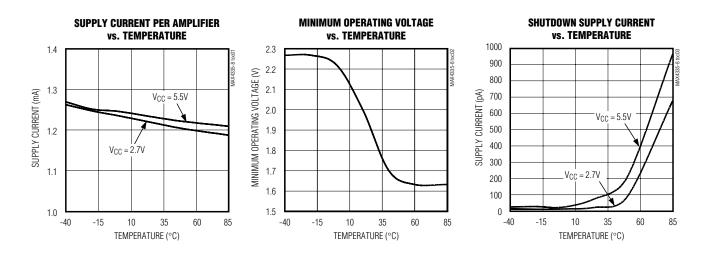
(V_{CC} = +2.7V, GND = 0, V_{CM} = V_{CC}/2, V_{OUT} = V_{CC}/2, V_{SHDN} = V_{CC}, A_{VCL} = 1V/V, C_L = 15pF, R_L = ∞ to V_{CC}/2, T_A = +25°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN TYP	MAX	UNITS	
Settling Time to 0.01%	ts	2V step	2		μs	
Crosstalk	CT	$V_{OUT} = 2V_{P-P}$; f = 1kHz	100		dB	
Input Capacitance	CIN		5		рF	
Input Voltage Neige Depoits		f = 10kHz	26		nV/√Hz	
Input Voltage-Noise Density	en	f = 1kHz			nv/vhz	
Input Current Noise Density	1	f = 10kHz	0.6		pA/√Hz	
Input Current-Noise Density	In	f = 1kHz			payvnz	
Capacitive-Load Stability		No sustained oscillation	200		рF	
Shutdown Time	TSHDN		1		μs	
Enable Time from Shutdown	t ENABLE		1		μs	
Power-Up Time	tON		5		μs	

Note 1: All devices are 100% production tested at $T_A = +25^{\circ}$ C. All limits over temperature are guaranteed by design.

_____Typical Operating Characteristics

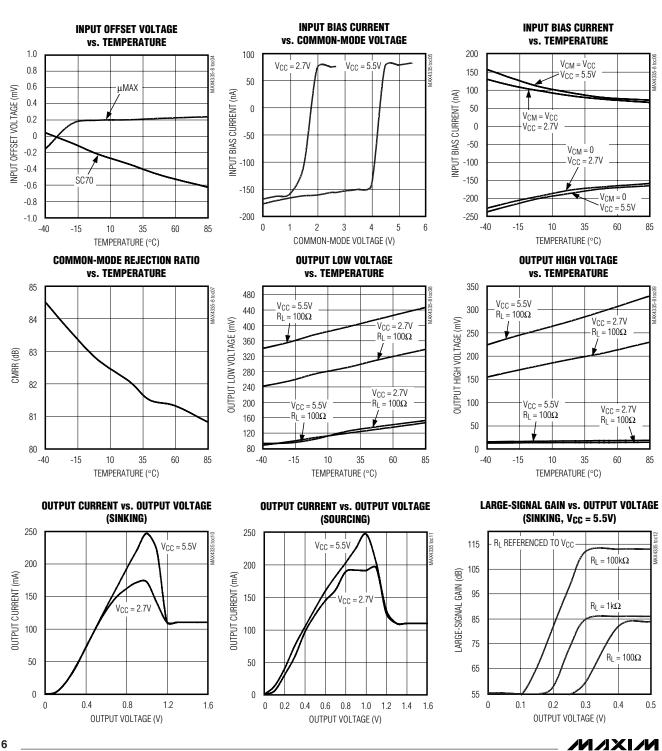
(V_{CC} = 2.7V, GND = 0, V_{CM} = 0, V_{OUT} = V_{CC}/2, R_L = ∞ to V_{CC}/2, V_{SHDN} = V_{CC}, T_A = +25°C, unless otherwise noted.)



(V_{CC} = 2.7V, GND = 0, V_{CM} = 0, V_{OUT} = V_{CC}/2, R_L = ∞ to V_{CC}/2, V_{SHDN} = V_{CC}, T_A = +25°C, unless otherwise noted.)

Typical Operating Characteristics (continued)

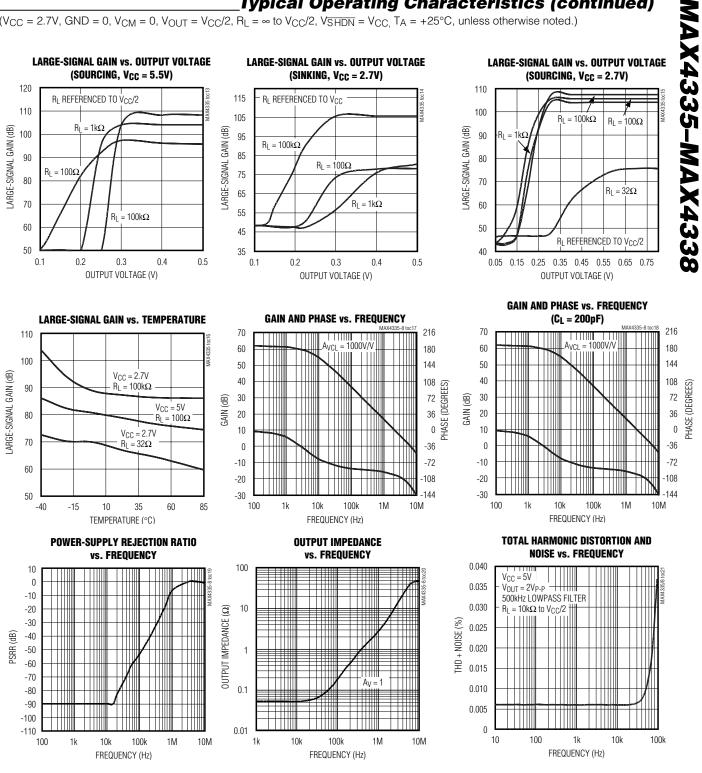
MAX4335-MAX4338



Typical Operating Characteristics (continued)

7

(V_{CC} = 2.7V, GND = 0, V_{CM} = 0, V_{OUT} = V_{CC}/2, R_L = ∞ to V_{CC}/2, V_{SHDN} = V_{CC}, T_A = +25°C, unless otherwise noted.)



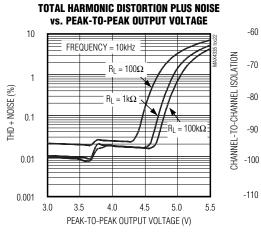
MIXIM

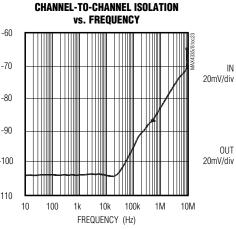


Typical Operating Characteristics (continued)

IN

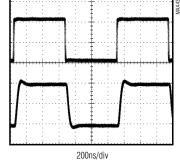
(V_{CC} = 2.7V, GND = 0, V_{CM} = 0, V_{OUT} = V_{CC}/2, R_L = ∞ to V_{CC}/2, V_{SHDN} = V_{CC}, T_A = +25°C, unless otherwise noted.)



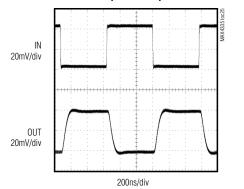


(NONINVERTING)

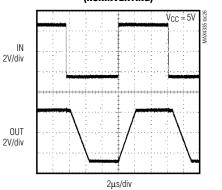
SMALL-SIGNAL TRANSIENT RESPONSE



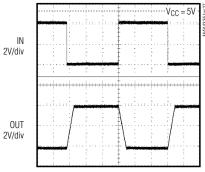
SMALL-SIGNAL TRANSIENT RESPONSE (INVERTING)



LARGE-SIGNAL TRANSIENT RESPONSE (NONINVERTING)

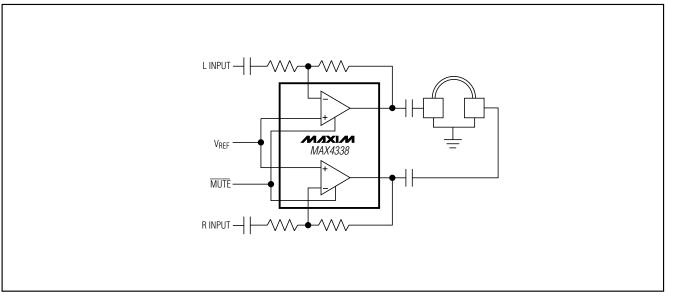


LARGE-SIGNAL TRANSIENT RESPONSE (INVERTING)



2µs/div

Typical Application Circuit



Pin Description

		PIN				
MAX4005	MAX4337		(4337			FUNCTION
MAX4335	MAX4336	SOT23	μΜΑΧ	MAX4338		
1	1	3, 5	3, 5	3, 7	IN1 ⁺ , IN2 ⁺	Noninverting Input
2	2	4	4	4	GND	Ground
3	3	2, 6	2, 6	2, 8	IN2 ⁻ , IN2 ⁻	Inverting Input
4	4	1, 7	1, 7	1, 9	OUT1, OUT2	Output(s)
5	—			—	N.C.	No Connection. Not internally connected.
	5			5, 6	SHDN1, SHDN2	Drive $\overline{\text{SHDN}}$ low for shutdown. Drive $\overline{\text{SHDN}}$ high or connect to V _{CC} for normal operation.
6	6	8	8	10	V _{CC}	Positive Supply

Applications Information

Package Power Dissipation Warning: Due to the high-output-current drive, this op amp can exceed the absolute maximum power-dissipation rating. As a general rule, as long as the peak current is less than or equal to 50mA, the maximum package power dissipation will not be exceeded for any of the package types offered. There are some exceptions to this rule, however. The absolute maximum power-dissipation rating of each package should always be verified using the following equations. The following equation gives an approximation of the package power dissipation:

 $P_{IC(DISS)} \cong V_{RMS} I_{RMS} COS \theta$

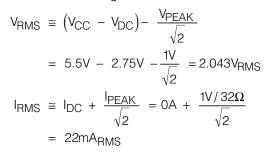
- where: V_{RMS} = the RMS voltage from V_{CC} to V_{OUT} when sourcing current
 - = the RMS voltage from VOUT to VEE when sinking current
 - I_{RMS} = the RMS current flowing out of or into the op amp and the load
 - θ = the phase difference between the voltage and the current. For resistive loads, COS θ = 1.

For example, the circuit in Figure 1 has a package power dissipation of 220mW.

$$V_{RMS} \cong \left(V_{CC} - V_{DC}\right) - \frac{V_{PEAK}}{\sqrt{2}}$$
$$= 5.5V - 2.75V - \frac{1V}{\sqrt{2}} = 2.043V_{RMS}$$
$$I_{RMS} \cong I_{DC} + \frac{I_{PEAK}}{\sqrt{2}} = \frac{2.75V}{32\Omega} + \frac{1V/32\Omega}{\sqrt{2}}$$
$$= 108mA_{RMS}$$

Therefore, $P_{IC(DISS)} = V_{RMS} I_{RMS} COS \theta = 220 mW$

Adding a coupling capacitor improves the package power dissipation because there is no DC current to the load, as shown in Figure 2.



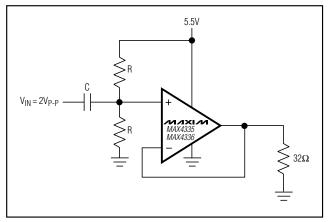


Figure 1. A Circuit Example where the MAX4335/MAX4336 is Dissipating High Power

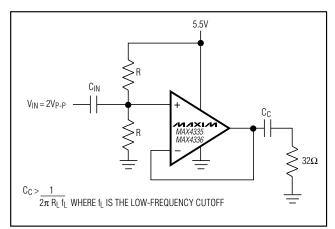


Figure 2. A Circuit Example where Adding a Coupling Capacitor Greatly Reduces the Power Dissipation of Its Package

Therefore, $P_{IC(DISS)} = V_{RMS} I_{RMS} COS \theta$ = 45mW

The absolute maximum power-dissipation rating of the package may be exceeded if the configuration in Figure 1 is used with the MAX4335/MAX4336 amplifiers at a high ambient temperature of $79^{\circ}C$ (220.6mW/°C plus a derating of 3.1mW/°C x $9^{\circ}C = 247.9$ mW). Note that the 247.9mW just exceeds the absolute maximum power dissipation of 245mW for the 6-pin SC70 package.

M/XI/M

Single-Supply Speaker Driver

The MAX4335/MAX4336 can be used as a single-supply speaker driver, as shown in the *Typical Operating Circuit*. Capacitor C1 is used for blocking DC (a 0.1µF ceramic capacitor can be used). When choosing resistors R3 and R4, take into consideration the input bias current as well as how much supply current can be tolerated. Choose resistors R1 and R2 according to the amount of gain and current desired. Capacitor C3 ensures unity gain for DC. A 10µF electrolytic capacitor is suitable for most applications. The coupling capacitor C2 sets a low-frequency pole and is fairly large in value. For a 32 Ω load, a 100µF coupling capacitor gives a low-frequency pole at 50Hz. The low-frequency pole can be set according to the following equation:

$f = 1 / 2\pi (R_LC2)$

Rail-to-Rail Input Stage

Devices in the MAX4335–MAX4338 family of highoutput-current amplifiers have rail-to-rail input and output stages designed for low-voltage, single-supply operation. The input stage consists of separate NPN and PNP differential stages that combine to provide an input common-mode range that extends 0.25V beyond the supply rails. The PNP stage is active for input voltages close to the negative rail, and the NPN stage is active for input voltages near the positive rail. The switchover transition region, which occurs near V_{CC}/2, has been extended to minimize the slight degradation in common-mode rejection ratio caused by mismatch of the input pairs.

Since the input stage switches between the NPN and PNP pairs, the input bias current changes polarity as the input voltage passes through the transition region. Match the effective impedance seen by each input to reduce the offset error caused by input bias currents flowing through external source impedances (Figures 3 and 5).

High source impedances, together with input capacitance, can create a parasitic pole that produces an underdamped signal response. Reducing the input impedance or placing a small (2pF to 10pF) capacitor across the feedback resistor improves response.

The MAX4335–MAX4338's inputs are protected from large differential input voltages by $1k\Omega$ series resistors and back-to-back double diodes across the inputs (Figure 5).

For differential voltages less than 1.2V, input resistance is typically $500k\Omega$. For differential input voltages greater than 1.2V, input resistance is approximately $8.4k\Omega$. The input bias current is given by the following equation:

$$I_{BIAS} = (V_{DIFF} - 1.2V) / 8.4k\Omega$$

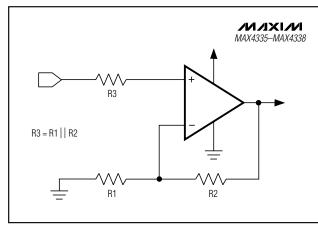


Figure 3. Reducing Offset Error Due to Bias Current (Noninverting)

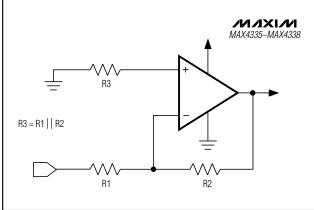


Figure 4. Reducing Offset Error Due to Bias Current (Inverting)

Rail-to-Rail Output Stage

The minimum output is within millivolts of ground for single-supply operation, where the load is referenced to ground (GND). Figure 6 shows the input voltage range and the output voltage swing of a MAX4335 connected as a voltage follower. The maximum output voltage swing is load dependent; however, it is guaranteed to be within 400mV of the positive rail (VCC = 2.7V) even with maximum load (32Ω to V_{CC}/2).

Driving Capacitive Loads

The MAX4335–MAX4338 have a high tolerance for capacitive loads. They are stable with capacitive loads up to 200pF. Figure 7 is a graph of the stable operating region for various capacitive loads vs. resistive loads.

MAX4335-MAX4338



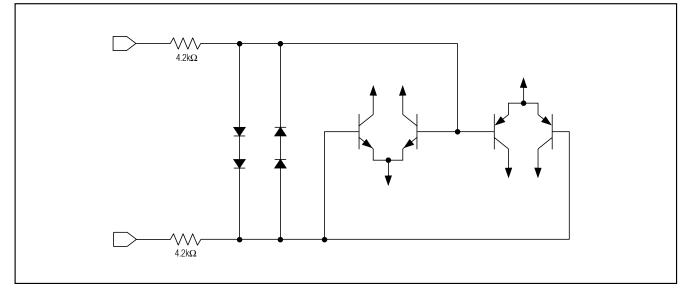


Figure 5. Input Protection Circuit

Figures 8 and 9 show the transient response with excessive capacitive loads (330pF), with and without the addition of an isolation resistor in series with the output. Figure 10 shows a typical noninverting capacitive-load-driving circuit in the unity-gain configuration. The resistor improves the circuit's phase margin by isolating the load capacitor from the op amp's output.

Power-Up and Shutdown/Mute Modes

The MAX4336/MAX4338 have a shutdown option. When the shutdown pin (SHDN) is pulled low, supply current drops to 0.04μ A per amplifier (V_{CC} = 5V), the amplifiers are disabled, and their <u>outputs</u> are placed in a high-impedance state. Pulling SHDN high enables the amplifier. In the dual MAX4338, the two amplifiers shut down independently. Figure 11 shows the MAX4336's output voltage response to a shutdown pulse. The MAX4335–MAX4338 typically settle within 5µs after power-up (Figure 12).

Power Supplies and Layout

The MAX4335–MAX4338 can operate from a single 2.7V to 5.5V supply. Bypass the power supply with a 0.1 μ F ceramic capacitor in parallel with at least 1 μ F. Good layout improves performance by decreasing the amount of stray capacitance at the op amps' inputs and outputs. Decrease stray capacitance by placing external components close to the op amps' input/output pins, minimizing trace and lead lengths.

Thermal Overload Protection

The MAX4335–MAX4338 includes thermal overload protection circuitry. When the junction temperature of the device exceeds +140°C, the supply current drops to 120µA per amplifier (V_{CC} = 5V) and the outputs are placed in a high-impedance state. The device returns to normal operation when the junction temperature falls to below +120°C.

Short-Circuit Current Protection

The MAX4335–MAX4338 incorporate a smart short-circuit protection feature. Figure 7 shows the output voltage region where the protection circuitry is active. A fault condition occurs when $I_{OUT} > 110$ mA and $V_{OUT} > 1V$ (sinking current) or when $I_{OUT} > 110$ mA and (V_{CC} - V_{OUT}) > 1V (sourcing current). When a fault is detected, the short-circuit protection circuitry is activated and the output current is limited to 110mA, protecting the device and the application circuitry. When the smart short circuit is not active, the output current can safely exceed 110mA (see the Output Current vs. Output Voltage Graph in the *Typical Operating Characteristics*).

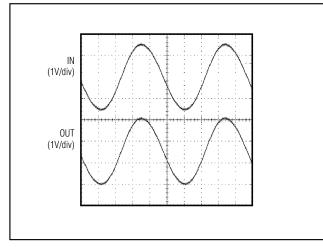


Figure 6. Rail-to-Rail Input/Output Range

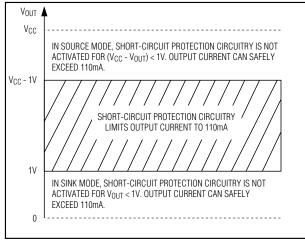


Figure 7. Short-Circuit Protection

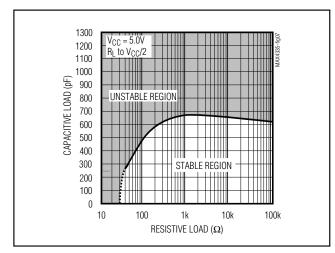


Figure 8. Capacitive-Load Stability

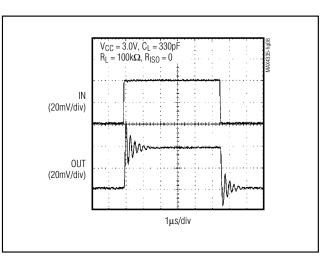


Figure 9. Small-Signal Transient Response with Excessive Capacitive Load



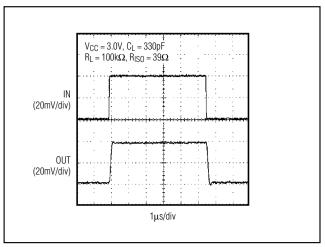


Figure 10. Small-Signal Transient Response with Excessive Capacitive Load with Isolation Resistor

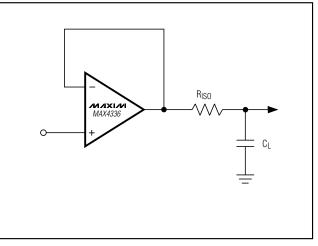


Figure 11. Capacitive-Load-Driving Circuit

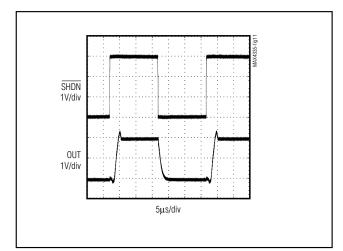


Figure 12. Shutdown Output Voltage Enable/Disable

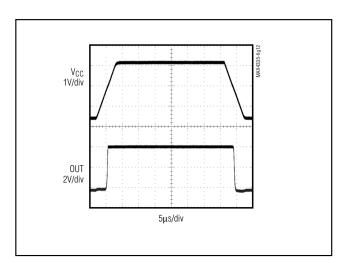
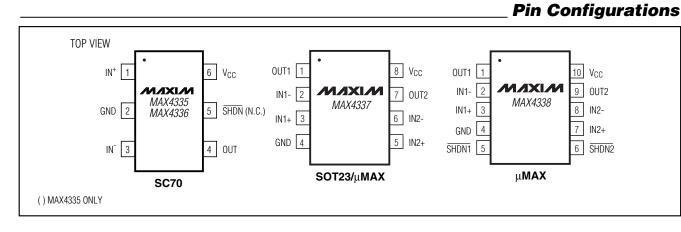


Figure 13. Power-Up/Down Output Voltage

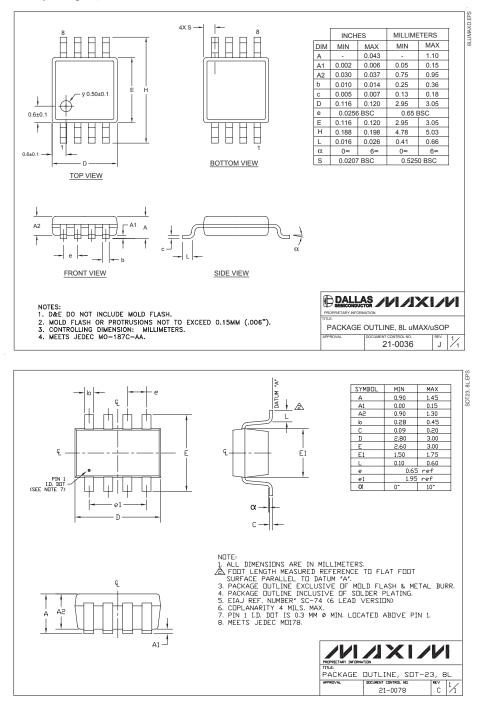


Chip Information

MAX4335 TRANSISTOR COUNT: 1200 MAX4336 TRANSISTOR COUNT: 1200 MAX4337 TRANSISTOR COUNT: 2400 MAX4338 TRANSISTOR COUNT: 2400 PROCESS: BICMOS

Package Information

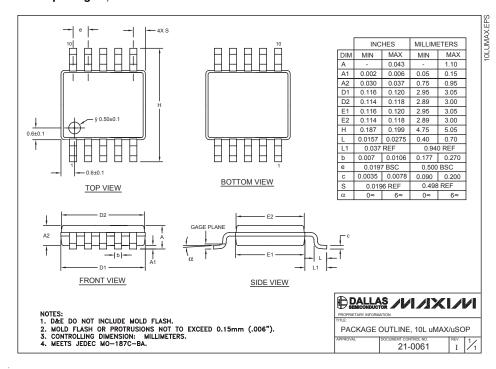
(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to **www.maxim-ic.com/packages**.)



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Package Information (continued)

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